Diode Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Glass

**Overall Length:** 

0.300 inches

# Terminal Length:

Between 1.000 inches and 1.500 inches

# **Overall Diameter:**

0.107 inches

#### **End Application:**

Aircraft, awacs, e-3a

## Mounting Facility Quantity:

2

#### Mounting Method:

Terminal

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

11.7 regulator voltage

## Voltage Tolerance In Percent:

-5.0/+5.0

# **Current Rating Per Characteristic:**

39.00 milliamperes repetitive peak forward current and 15.00 microamperes forward current, average peak

## **Power Rating Per Characteristic:**

500.0 milliwatts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

## **Special Features:**

Voltage-reference type

## Test Data Document:

81349-mil-prf-19500/157 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

2 uninsulated wire lead

# Shelf Life:

N/a

## Unit Of Measure:

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#### **Demilitarization:**

No

Fiig:

A110a0

# Mil-std (military Standard):

Mil-prf-19500 spec.